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- High Capacitive-Drive Capability
- 'ALS832A Has Typical Delay Time of 4.8 ns (C_L = 50 pF) and Typical Power Dissipation of 4.5 mW Per Gate
- 'AS832B Has Typical Delay Time of 3.2 ns (C_L = 50 pF) and Typical Power Dissipation of Less Than 13 mW Per Gate
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

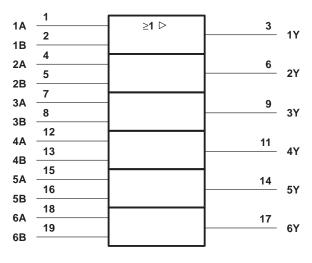
These devices contain six independent 2-input OR drivers. They perform the Boolean functions Y = A + B or $Y = \overline{A \cdot B}$ in positive logic.

The SN54ALS832A and SN54AS832B are characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ALS832A and SN74AS832B are characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each driver)

INP	UTS	OUTPUT
А	В	Y
н	Х	Н
X	Н	Н
L	L	L

logic symbol[†]



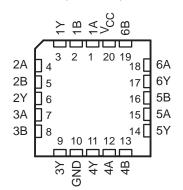
⁺ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

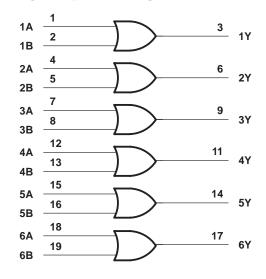


SN54ALS832A, SN54AS832B . . . J PACKAGE SN74ALS832A, SN74AS832B . . . DW OR N PACKAGE (TOP VIEW)

SN54ALS832A, SN54AS832B . . . FK PACKAGE (TOP VIEW)



logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{CC}	
Input voltage, V _I	/ V
Operating free-air temperature range, T _A : SN54ALS832A	–55°C to 125°C
SN74ALS832A	0°C to 70°C
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN5	54ALS83	2A	SN7	4ALS83	2A	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.7			0.8	V
IOH	High-level output current			-12			-15	mA
IOL	Low-level output current			12			24	mA
TA	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			4ALS83	2A	SN7	2A		
PARAMETER	TEST CC	MIN	typ‡	MAX	MIN	typ‡	MAX	UNIT	
VIK	V _{CC} = 4.5 V,	lı = -18 mA			-1.5			-1.5	V
	V_{CC} = 4.5 V to 5.5 V,	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2	2		V _{CC} -2	2		
VOH		$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		V
VОН	$V_{CC} = 4.5 V$	I _{OH} = -12 mA	2						v
		I _{OH} = -15 mA				2			
VOL	V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
VOL	VCC = 4.5 V	I _{OL} = 24 mA					0.35	0.5	v
l	V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
ЧΗ	V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ
١ _{١L}	V _{CC} = 5.5 V,	$V_{I} = 0.4 V$			-0.1			-0.1	mA
١O§	V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA
IССН	V _{CC} = 5.5 V,	V _I = 4.5 V		6	9		6	9	mA
ICCL	V _{CC} = 5.5 V,	$V_{I} = 0$		9.5	16		9.5	16	mA

[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C.

\$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.



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switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	ν ₍ Cլ Rլ Τρ	UNIT			
			SN54AL	S832A	SN74AL	S832A	
			MIN	MAX	MIN	MAX	
^t PLH	A or B	v	1	13	2	9	
^t PHL		· ·	1	11	1	8	ns

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage, V _{CC}	
Operating free-air temperature range, T _A : SN54AS832B	-55°C to 125°C
SN74AS832B	0°C to 70°C
Storage temperature range	-65°C to 150°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions§

		SN	54AS832	2B	SN	74AS832	2B	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
ЮН	High-level output current			-40			-48	mA
IOL	Low-level output current			40			48	mA
TA	Operating free-air temperature	-55		125	0		70	°C

§ These high sink- or source-current devices are not recommended for use above 40 MHz.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			54AS832	2B	SN7	2B	UNIT	
PARAMETER	TEST CO	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT	
VIK	V _{CC} = 4.5 V,	lı = -18 mA			-1.2			-1.2	V
	V_{CC} = 4.5 V to 5.5 V,	$I_{OH} = -2 \text{ mA}$	V _{CC} -2			V _{CC} -2			
Vou		$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		V
VOH	V _{CC} = 4.5 V	$I_{OH} = -40 \text{ mA}$	2						v
		$I_{OH} = -48 \text{ mA}$				2			
Ve	V _{CC} = 4.5 V	I _{OL} = 40 mA		0.25	0.5				V
VOL	VCC = 4.5 V	I _{OL} = 48 mA					0.35	0.5	v
lį	V _{CC} = 5.5 V,	$V_{I} = 7 V$			0.1			0.1	mA
ΙΗ	V _{CC} = 5.5 V,	VI = 2.7 V			20			20	μA
١	V _{CC} = 5.5 V,	V _I = 0.4 V			-0.5			-0.5	mA
۱ ₀ ‡	V _{CC} = 5.5 V,	V _O = 2.25 V	-50		-200	-50		-200	mA
Іссн	V _{CC} = 5.5 V,	VI = 4.5 V		11	17		11	17	mA
ICCL	V _{CC} = 5.5 V,	$V_{I} = 0$		22	36		22	36	mA

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

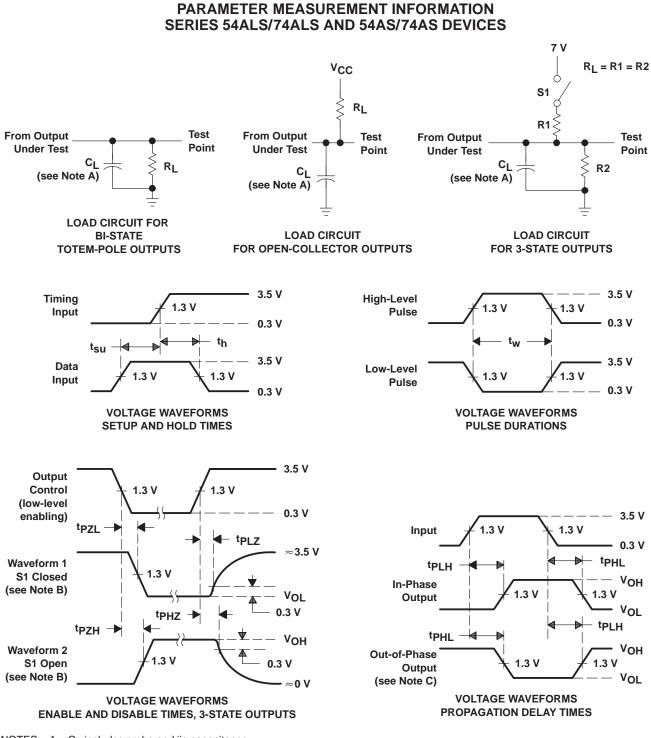
switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	VC CL RL TA	UNIT			
			SN54A	S832B	SN74A	S832B	
			MIN	MAX	MIN	MAX	
^t PLH	A or B	v	1	7.5	1	6.3	ns
^t PHL			1	7	1	6.3	115

§ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



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NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR \leq 1 MHz, t_{f} = t_{f} = 2 ns, duty cycle = 50\%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-88523012A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 88523012A SNJ54AS 832BFK	Samples
8414501RA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8414501RA SNJ54ALS832AJ	Samples
SN54ALS832AJ	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54ALS832AJ	Samples
SN74ALS832ADW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS832A	Samples
SN74ALS832AN	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN74ALS832AN	Samples
SN74AS832BDW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS832B	Samples
SN74AS832BDWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS832B	Samples
SN74AS832BDWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS832B	Samples
SN74AS832BN	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN74AS832BN	Samples
SN74AS832BNE4	ACTIVE	PDIP	Ν	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN74AS832BN	Samples
SNJ54ALS832AJ	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8414501RA SNJ54ALS832AJ	Samples
SNJ54AS832BFK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 88523012A SNJ54AS 832BFK	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



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⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54ALS832A, SN54AS832B, SN74ALS832A, SN74AS832B :

- Catalog : SN74ALS832A, SN74AS832B
- Military : SN54ALS832A, SN54AS832B

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AS832BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AS832BDWR	SOIC	DW	20	2000	367.0	367.0	45.0

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. This package can be hermetically sealed with a metal lid.

D. Falls within JEDEC MS-004



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